

Negative Voltage Regulators

1.0 A

MC7900 Series

The MC7900 series of fixed output negative voltage regulators are intended as complements to the popular MC7800 series devices. These negative regulators are available in the same seven–voltage options as the MC7800 devices. In addition, one extra voltage option commonly employed in MECL systems is also available in the negative MC7900 series.

Available in fixed output voltage options from -5.0 V to -24 V, these regulators employ current limiting, thermal shutdown, and safe-area compensation – making them remarkably rugged under most operating conditions. With adequate heatsinking they can deliver output currents in excess of 1.0 A.

- No External Components Required
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting
- Output Transistor Safe-Area Compensation
- Available in 2% Voltage Tolerance (See Ordering Information)
- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish

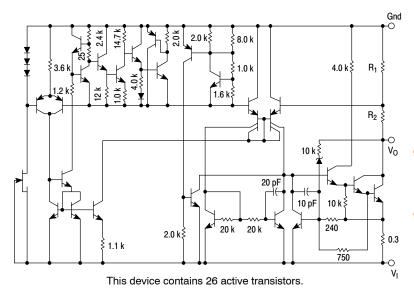
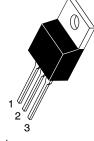


Figure 1. Representative Schematic Diagram

TO-220 T SUFFIX CASE 221AB

Heatsink surface connected to Pin 2.



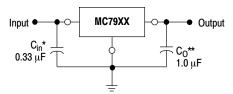
Pin 1. Ground 2. Input 3. Output

D²PAK D2T SUFFIX CASE 936



Heatsink surface (shown as terminal 4 in case outline drawing) is connected to Pin 2.

STANDARD APPLICATION



A common ground is required between the input and the output voltages. The input voltage must remain typically 2.0 V above more negative even during the high point of the input ripple voltage.

- XX, These two digits of the type number indicate nominal voltage.
 - * C_{in} is required if regulator is located an appreciable distance from power supply filter.
 - ** CO improve stability and transient response.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 12 of this data sheet.

MAXIMUM RATINGS ($T_A = +25^{\circ}C$, unless otherwise noted.)

Rating	Symbol	Value	Unit
Input Voltage $(-5.0 \text{ V} \ge \text{V}_{\text{O}} \ge -18 \text{ V})$ (24 V)	V _I	-35 -40	Vdc
Power Dissipation Case 221A			
$T_A = +25^{\circ}\text{C}$ Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case Case 936 (D ² PAK)	P _D θ _{JA} θ _{JC}	Internally Limited 65 5.0	W °C/W °C/W
T _A = +25°C Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case	P_{D} θ_{JA} θ_{JC}	Internally Limited 70 5.0	W °C/W °C/W
Storage Junction Temperature Range	T _{stg}	-65 to +150	°C
Junction Temperature	TJ	+150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
*This device series contains ESD protection and exceeds the following tests:

Human Body Model 2000 V per MIL_STD_883, Method 3015 Machine Model Method 200 V

MC7905B, MC7905C

 $\textbf{ELECTRICAL CHARACTERISTICS} \ (V_I = -10 \ V, \ I_O = 500 \ \text{mA}, \ Tlow^* < T_J < +125 ^{\circ}C, \ unless \ otherwise \ noted.)$

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	V _O	-4.8	-5.0	-5.2	Vdc
Line Regulation (Note 1) (T _J = +25°C, I _O = 100 mA)	Reg _{line}				mV
$-7.0 \text{ Vdc} \ge V_1 \ge -25 \text{ Vdc}$		_	7.0	50	
$-8.0 \text{ Vdc} \ge V_1 \ge -12 \text{ Vdc}$ $(T_J = +25^{\circ}\text{C}, I_O = 500 \text{ mA})$		_	2.0	25	
$-7.0 \text{ Vdc} \ge V_1 \ge -25 \text{ Vdc}$		_	35	100	
$-8.0 \text{ Vdc} \ge V_1 \ge -12 \text{ Vdc}$		_	8.0	50	
Load Regulation, T _J = +25°C (Note 1)	Reg _{load}				mV
$5.0 \text{ mA} \le I_0 \le 1.5 \text{ A}$		_	11	100	
250 mA ≤ I _O ≤ 750 mA		_	4.0	50	
Output Voltage	V _O	-4.75		-5.25	Vdc
$-7.0 \text{ Vdc} \ge V_{\text{I}} \ge -20 \text{ Vdc}, 5.0 \text{ mA} \le I_{\text{O}} \le 1.0 \text{ A}, P \le 15 \text{ W}$		-4.75	_		
Input Bias Current (T _J = +25°C)	I _{IB}	_	4.3	8.0	mA
Input Bias Current Change	ΔI_IB				mA
$-7.0 \text{ Vdc} \ge V_1 \ge -25 \text{ Vdc}$		_	-	1.3 0.5	
5.0 mA ≤ I _O ≤ 1.5 A		_	_	0.5	
Output Noise Voltage ($T_A = +25^{\circ}C$, 10 Hz \leq f \leq 100 kHz)	V _n	_	40	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	_	70	-	dB
Dropout Voltage	V_{I} – V_{O}				Vdc
$I_{O} = 1.0 \text{ A}, T_{J} = +25^{\circ}\text{C}$		_	1.3	_	
Average Temperature Coefficient of Output Voltage	$\Delta V_{O}/\Delta T$				mV/°C
$I_{O} = 5.0 \text{ mA}, \text{ Tlow*} \le T_{J} \le +125^{\circ}\text{C}$		_	-1.0	_	

 $^{1. \ \} Load \ and \ line \ regulation \ are \ specified \ at \ constant \ junction \ temperature. \ Changes \ in \ V_O \ due \ to \ heating \ effects \ must \ be \ taken \ into \ account$ separately. Pulse testing with low duty cycle is used.

^{*}Tlow = -40° C for MC7905B and Tlow = 0° C for MC7905C.

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	-4.9	-5.0	-5.1	Vdc
Line Regulation (Note 2) $-8.0 \text{ Vdc} \ge V_I \ge -12 \text{ Vdc}$; $I_O = 1.0 \text{ A}$, $T_J = +25^{\circ}\text{C}$ $-8.0 \text{ Vdc} \ge V_I \ge -12 \text{ Vdc}$; $I_O = 1.0 \text{ A}$ $-7.5 \text{ Vdc} \ge V_I \ge -25 \text{ Vdc}$; $I_O = 500 \text{ mA}$ $-7.0 \text{ Vdc} \ge V_I \ge -20 \text{ Vdc}$; $I_O = 1.0 \text{ A}$, $T_J = +25^{\circ}\text{C}$	Reg _{line}	- - - -	2.0 7.0 7.0 6.0	25 50 50 50	mV
Load Regulation (Note 2) 5.0 mA \leq I _O \leq 1.5 A, T _J = +25°C 250 mA \leq I _O \leq 750 mA 5.0 mA \leq I _O \leq 1.0 A	Reg _{load}	- - -	11 4.0 9.0	100 50 100	mV
Output Voltage $-7.5 \text{ Vdc} \ge V_l \ge -20 \text{ Vdc}, 5.0 \text{ mA} \le I_O \le 1.0 \text{ A}, \text{ P} \le 15 \text{ W}$	V _O	-4.80	-	-5.20	Vdc
Input Bias Current	I _{IB}	-	4.4	8.0	mA
Input Bias Current Change -7.5 Vdc \ge V _I \ge -25 Vdc 5.0 mA \le I _O \le 1.0 A 5.0 mA \le I _O \le 1.5 A, T _J = +25°C	Δl _{IB}	- - -	- - -	1.3 0.5 0.5	mA
Output Noise Voltage ($T_A = +25^{\circ}C$, 10 Hz \leq f \leq 100 kHz)	V _n	-	40	-	μV
Ripple Rejection (I _O = mA, f = 120 Hz)	RR	-	70	-	dB
Dropout Voltage (I _O = 1.0 A. T _J = +25°C)	V_I – V_O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0$ mA, $0^{\circ}C \le T_J \le +125^{\circ}C$	$\Delta V_{O}/\Delta T$	_	-1.0	_	mV/°C

$\label{eq:continuous} \textbf{MC7905.2C}$ $\textbf{ELECTRICAL CHARACTERISTICS} \ (V_I = -10 \ V, \ I_O = 500 \ mA, \ 0^{\circ}C < T_J < +125^{\circ}C, \ unless \ otherwise \ noted.)$

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	-5.0	-5.2	-5.4	Vdc
Line Regulation (Note 2) (T _{.I} = +25°C, I _O = 100 mA)	Reg _{line}				mV
-7.2 Vdc ≥ V _I ≥ -25 Vdc		-	8.0	52	
$-8.0 \text{ Vdc} \ge V_1 \ge -12 \text{ Vdc}$ $(T_J = +25^{\circ}\text{C}, I_O = 500 \text{ mA})$		-	2.2	27	
$-7.2 \text{ Vdc} \ge V_1 \ge -25 \text{ Vdc}$		-	37	105	
$-8.0 \text{ Vdc} \ge V_{\text{I}} \ge -12 \text{ Vdc}$		-	8.5	52	
Load Regulation, T _J = +25°C (Note 2)	Reg _{load}			405	mV
$5.0 \text{ mA} \le I_0 \le 1.5 \text{ A}$		_	12 4.5	105 52	
250 mA ≤ I _O ≤ 750 mA		_	4.5	52	
Output Voltage $-7.2 \text{ Vdc} \ge V_l \ge -20 \text{ Vdc}$, 5.0 mA $\le I_O \le 1.0 \text{ A}$, P $\le 15 \text{ W}$	Vo	-4.95	_	-5.45	Vdc
Input Bias Current (T _J = +25°C)	I _{IB}	-	4.3	8.0	mA
Input Bias Current Change $-7.2 \text{ Vdc} \ge \text{V}_1 \ge -25 \text{ Vdc}$	Δl_{IB}	-	-	1.3	mA
5.0 mA ≤ I _O ≤ 1.5 A		_	_	0.5	
Output Noise Voltage (T_A = +25°C, 10 Hz \leq f \leq 100 kHz)	V_n	-	42	_	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	68	-	dB
Dropout Voltage (I _O = 1.0 A, T _J = +25°C)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0$ mA, $0^{\circ}C \le T_J \le +125^{\circ}C$	$\Delta V_{O}/\Delta T$	-	-1.0	_	mV/°C

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

 $\label{eq:continuous} \textbf{MC7906C} \\ \textbf{ELECTRICAL CHARACTERISTICS} \ (V_I = -11 \ V, \ I_O = 500 \ mA, \ 0^{\circ}C < T_J < +125^{\circ}C, \ unless \ otherwise \ noted.)$

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	-5.75	-6.0	-6.25	Vdc
Line Regulation (Note 3) (T _J = +25°C, I _O = 100 mA)	Reg _{line}				mV
$-8.0 \text{ Vdc} \ge \text{V}_1 \ge -25 \text{ Vdc}$		-	9.0	60	
$-9.0 \text{ Vdc} \ge V_1 \ge -13 \text{ Vdc}$ $(T_{.1} = +25^{\circ}\text{C}, I_{.0} = 500 \text{ mA})$		-	3.0	30	
$-8.0 \text{ Vdc} \ge V_1 \ge -25 \text{ Vdc}$		_	43	120	
-9.0 Vdc ≥ V ₁ ≥ -13 Vdc		-	10	60	
Load Regulation, T _J = +25°C (Note 3)	Reg _{load}				mV
$5.0 \text{ mA} \le I_0 \le 1.5 \text{ A}$		-	13	120	
250 mA ≤ I _O ≤ 750 mA		_	5.0	60	
Output Voltage $-8.0 \text{ Vdc} \ge V_l \ge -21 \text{ Vdc}, 5.0 \text{ mA} \le I_O \le 1.0 \text{ A}, \text{ P} \le 15 \text{ W}$	V _O	-5.7	-	-6.3	Vdc
Input Bias Current (T _J = +25°C)	I _{IB}	-	4.3	8.0	mA
Input Bias Current Change	ΔI_{IB}				mA
$-8.0 \text{ Vdc} \ge \text{V}_1 \ge -25 \text{ Vdc}$		_	_	1.3	
5.0 mA ≤ I _O ≤ 1.5 A		_	_	0.5	
Output Noise Voltage ($T_A = +25^{\circ}C$, 10 Hz $\leq f \leq$ 100 kHz)	V_n	_	45	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	65	_	dB
Dropout Voltage (I _O = 1.0 A, T _J = +25°C)	V _I -V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0$ mA, $0^{\circ}C \le T_J \le +125^{\circ}C$	$\Delta V_{O}/\Delta T$	_	-1.0	-	mV/°C

MC7908C

ELECTRICAL CHARACTERISTICS ($V_I = -14 \text{ V}, I_O = 500 \text{ mA}, 0^{\circ}\text{C} < T_J < +125^{\circ}\text{C}, \text{ unless otherwise noted.}$)

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	-7.7	-8.0	-8.3	Vdc
Line Regulation (Note 3) (T _{.I} = +25°C, I _O = 100 mA)	Reg _{line}				mV
-10.5 Vdc ≥ V _I ≥ -25 Vdc		_	12	80	
$-11 \text{ Vdc} \ge V_1 \ge -17 \text{ Vdc}$ (T _{,1} = +25°C, I _O = 500 mA)		-	5.0	40	
(1) = +25 C, 10 = 500 Hz) -10.5 Vdc $\geq \text{V}_1 \geq -25 \text{ Vdc}$ -11 Vdc $\geq \text{V}_1 \geq -17 \text{ Vdc}$		- -	50 22	160 80	
Load Regulation, T _J = +25°C (Note 3)	Reg _{load}				mV
$5.0 \text{ mA} \le I_0 \le 1.5 \text{ A}$		_	26	160	
$250 \text{ mA} \le I_0 \le 750 \text{ mA}$		_	9.0	80	
Output Voltage $-10.5 \text{ Vdc} \ge V_I \ge -23 \text{ Vdc}, 5.0 \text{ mA} \le I_O \le 1.0 \text{ A}, \text{ P} \le 15 \text{ W}$	V _O	-7.6	_	-8.4	Vdc
Input Bias Current (T _J = +25°C)	I _{IB}	-	4.3	8.0	mA
Input Bias Current Change -10.5 Vdc \geq V _I \geq -25 Vdc 5.0 mA \leq I _O \leq 1.5 A	$\Delta l_{ m IB}$	_ _	_ _	1.0 0.5	mA
Output Noise Voltage ($T_A = +25^{\circ}C$, 10 Hz \leq f \leq 100 kHz)	V _n	-	52	_	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	62	-	dB
Dropout Voltage (I _O = 1.0 A, T _J = +25°C)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O=5.0$ mA, $0^{\circ}C \leq T_J \leq +125^{\circ}C$	$\Delta V_{O}/\Delta T$	_	-1.0	-	mV/°C

^{3.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

MC7912B, MC7912C ELECTRICAL CHARACTERISTICS (V_I = -19 V, I_O = 500 mA, Tlow* < T_J < +125°C, unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	-11.5	-12	-12.5	Vdc
Line Regulation (Note 4) (T _J = +25°C, I _O = 100 mA)	Reg _{line}				mV
$-14.5 \text{ Vdc} \ge V_1 \ge -30 \text{ Vdc}$		-	13	120	
$-16 \text{ Vdc} \ge V_1 \ge -22 \text{ Vdc}$		_	6.0	60	
$(T_J = +25^{\circ}C, I_O = 500 \text{ mA})$ -14.5 Vdc $\geq V_I \geq -30 \text{ Vdc}$		_	55	240	
-16 Vdc ≥ V _I ≥ -22 Vdc		-	24	120	
Load Regulation, T _J = +25°C (Note 4)	Reg _{load}				mV
$5.0 \text{ mA} \le I_0 \le 1.5 \text{ A}$		-	46	240	
$250 \text{ mA} \le I_0 \le 750 \text{ mA}$		-	17	120	
Output Voltage	Vo				Vdc
$-14.5 \text{ Vdc} \ge V_{\text{I}} \ge -27 \text{ Vdc}, 5.0 \text{ mA} \le I_{\text{O}} \le 1.0 \text{ A}, P \le 15 \text{ W}$		-11.4	_	-12.6	
Input Bias Current ($T_J = +25^{\circ}C$)	I _{IB}	-	4.4	8.0	mA
Input Bias Current Change	Δl_{IB}				mA
$-14.5 \text{ Vdc} \ge V_1 \ge -30 \text{ Vdc}$		-	-	1.0	
5.0 mA ≤ I _O ≤ 1.5 A		-	-	0.5	
Output Noise Voltage ($T_A = +25^{\circ}C$, 10 Hz $\leq f \leq$ 100 kHz)	V _n	-	75	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	61	-	dB
Dropout Voltage (I _O = 1.0 A, T _J = +25°C)	V_{I} – V_{O}	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage	$\Delta V_{O}/\Delta T$				mV/°C
$I_{O} = 5.0 \text{ mA}, \text{Tlow*} \le T_{J} \le +125^{\circ}\text{C}$		-	-1.0	-	

MC7912AC

$\textbf{ELECTRICAL CHARACTERISTICS} \ (V_I = -19 \ V, \ I_O = 500 \ \text{mA}, \ Tlow^* < T_J < +125 ^{\circ}C, \ unless \ otherwise \ noted.)$

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	-11.75	-12	-12.25	Vdc
Line Regulation (Note 4) $-16 \text{ Vdc} \ge V_I \ge -22 \text{ Vdc}$; $I_O = 1.0 \text{ A}$, $T_J = +25^{\circ}\text{C}$ $-16 \text{ Vdc} \ge V_I \ge -22 \text{ Vdc}$; $I_O = 1.0 \text{ A}$ $-14.8 \text{ Vdc} \ge V_I \ge -30 \text{ Vdc}$; $I_O = 500 \text{ mA}$ $-14.5 \text{ Vdc} \ge V_I \ge -27 \text{ Vdc}$; $I_O = 1.0 \text{ A}$, $T_J = +25^{\circ}\text{C}$	Reg _{line}	- - - -	6.0 24 24 13	60 120 120 120	mV
Load Regulation (Note 4) 5.0 mA \leq I _O \leq 1.5 A, T _J = +25°C 250 mA \leq I _O \leq 750 mA 5.0 mA \leq I _O \leq 1.0 A	Reg _{load}	- - -	46 17 35	150 75 150	mV
Output Voltage $-14.8 \text{ Vdc} \ge V_I \ge -27 \text{ Vdc}, 5.0 \text{ mA} \le I_O \le 1.0 \text{ A, P} \le 15 \text{ W}$	Vo	-11.5	-	-12.5	Vdc
Input Bias Current	I _{IB}	-	4.4	8.0	mA
Input Bias Current Change -15 Vdc \geq V _I \geq -30 Vdc 5.0 mA \leq I _O \leq 1.0 A 5.0 mA \leq I _O \leq 1.5 A, T _J = $+25^{\circ}$ C	ΔI _{IB}	- - -	- - -	0.8 0.5 0.5	mA
Output Noise Voltage ($T_A = +25^{\circ}C$, 10 Hz $\leq f \leq$ 100 kHz)	V _n	-	75	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	61	_	dB
Dropout Voltage (I _O = 1.0 A, T _J = +25°C)	V _I –V _O	-	1.3	_	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0$ mA, Tlow* $\leq T_J \leq +125$ °C	$\Delta V_{O}/\Delta T$	_	-1.0	_	mV/°C

Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

^{*}Tlow = -40°C for MC7912B and Tlow = 0°C for MC7912C.

MC7915B, MC7915C **ELECTRICAL CHARACTERISTICS** (V_I = -23 V, I_O = 500 mA, Tlow* < T_J < +125°C, unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	V _O	-14.4	-15	-15.6	Vdc
Line Regulation (Note 5) (T _{.I} = +25°C, I _O = 100 mA)	Reg _{line}				mV
$-17.5 \text{ Vdc} \ge V_1 \ge -30 \text{ Vdc}$ $-20 \text{ Vdc} \ge V_1 \ge -26 \text{ Vdc}$ $(T_{.1} = +25^{\circ}\text{C}, I_{.0} = 500 \text{ mA})$		- -	14 6.0	150 75	
$-17.5 \text{ Vdc} \ge V_1 \ge -30 \text{ Vdc}$ $-20 \text{ Vdc} \ge V_1 \ge -26 \text{ Vdc}$		- -	57 27	300 150	
Load Regulation, $T_J = +25^{\circ}C$ (Note 5) 5.0 mA $\leq I_O \leq$ 1.5 A 250 mA $\leq I_O \leq$ 750 mA	Reg _{load}	- -	68 25	300 150	mV
Output Voltage $-17.5 \text{ Vdc} \ge V_l \ge -30 \text{ Vdc}$, 5.0 mA $\le I_O \le 1.0 \text{ A}$, P $\le 15 \text{ W}$	Vo	-14.25	-	-15.75	Vdc
Input Bias Current (T _J = +25°C)	I _{IB}	-	4.4	8.0	mA
Input Bias Current Change $-17.5 \text{ Vdc} \ge V_1 \ge -30 \text{ Vdc}$ $5.0 \text{ mA} \le I_0 \le 1.5 \text{ A}$	Δl_{IB}	- -	- -	1.0 0.5	mA
Output Noise Voltage ($T_A = +25^{\circ}C$, 10 Hz \leq f \leq 100 kHz)	V _n	_	90	_	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	_	60	_	dB
Dropout Voltage (I _O = 1.0 A, T _J = +25°C)	V_I – V_O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0$ mA, Tlow* $\leq T_J \leq +125$ °C	$\Delta V_{O}/\Delta T$	-	-1.0	-	mV/°C

MC7915AC

$\textbf{ELECTRICAL CHARACTERISTICS} \ (V_I = -23 \ V, \ I_O = 500 \ \text{mA}, \ Tlow^* < T_J < +125^{\circ}C, \ unless \ otherwise \ noted.)$

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	-14.7	-15	-15.3	Vdc
Line Regulation (Note 5) $-20 \text{ Vdc} \ge V_I \ge -26 \text{ Vdc}, I_O = 1.0 \text{ A}, T_J = +25^{\circ}\text{C}$ $-20 \text{ Vdc} \ge V_I \ge -26 \text{ Vdc}, I_O = 1.0 \text{ A},$ $-17.9 \text{ Vdc} \ge V_I \ge -30 \text{ Vdc}, I_O = 500 \text{ mA}$ $-17.5 \text{ Vdc} \ge V_I \ge -30 \text{ Vdc}, I_O = 1.0 \text{ A}, T_J = +25^{\circ}\text{C}$	Reg _{line}	- - -	27 57 57 57	75 150 150 150	mV
Load Regulation (Note 5) 5.0 mA \leq I _O \leq 1.5 A, T _J = +25°C 250 mA \leq I _O \leq 750 mA 5.0 mA \leq I _O \leq 1.0 A	Reg _{load}	- - -	68 25 40	150 75 150	mV
Output Voltage $-17.9 \text{ Vdc} \ge V_I \ge -30 \text{ Vdc, } 5.0 \text{ mA} \le I_O \le 1.0 \text{ A, } P \le 15 \text{ W}$	Vo	-14.4	-	-15.6	Vdc
Input Bias Current	I _{IB}	-	4.4	8.0	mA
Input Bias Current Change $-17.5 \text{ Vdc} \ge V_I \ge -30 \text{ Vdc}$ $5.0 \text{ mA} \le I_O \le 1.0 \text{ A}$ $5.0 \text{ mA} \le I_O \le 1.5 \text{ A}, T_J = +25^{\circ}\text{C}$	Δl_{IB}	- - -	- - -	0.8 0.5 0.5	mA
Output Noise Voltage ($T_A = +25^{\circ}C$, 10 Hz \leq f \leq 100 kHz)	V _n	-	90	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	60	-	dB
Dropout Voltage (I _O = 1.0 A, T _J = +25°C)	V _I –V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage $I_O = 5.0$ mA, Tlow* $\leq T_J \leq +125^{\circ}C$	$\Delta V_{O}/\Delta T$	_	-1.0	_	mV/°C

^{5.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

^{*}Tlow = -40° C for MC7915B and Tlow = 0° C for MC7915C.

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	-17.3	-18	-18.7	Vdc
Line Regulation (Note 6) (T _{.I} = +25°C, I _O = 100 mA)	Reg _{line}				mV
-21 Vdc ≥ V _I ≥ -33 Vdc		-	25	180	
$-24 \text{ Vdc} \ge V_1 \ge -30 \text{ Vdc}$ $(T_1 + 25 \text{ Color}) = 500 \text{ m/s}$		-	10	90	
$(T_J = +25^{\circ}C, I_O = 500 \text{ mA})$ -21 Vdc $\geq V_I \geq -33 \text{ Vdc}$		_	90	360	
$-24 \text{ Vdc} \ge V_1 \ge -30 \text{ Vdc}$		-	50	180	
Load Regulation, T _J = +25°C (Note 6)	Reg _{load}				mV
$5.0 \text{ mA} \le I_0 \le 1.5 \text{ A}$		-	110	360	
250 mA ≤ I _O ≤ 750 mA		-	55	180	
Output Voltage	Vo				Vdc
$-21 \text{ Vdc} \ge \text{V}_1 \ge -33 \text{ Vdc}, 5.0 \text{ mA} \le \text{I}_0 \le 1.0 \text{ A}, \text{ P} \le 15 \text{ W}$		-17.1	_	-18.9	
Input Bias Current ($T_J = +25^{\circ}C$)	I _{IB}	-	4.5	8.0	mA
Input Bias Current Change	Δl_{IB}				mA
$-21 \text{ Vdc} \ge V_1 \ge -33 \text{ Vdc}$		-	-	1.0	
5.0 mA ≤ I _O ≤ 1.5 A		-	-	0.5	
Output Noise Voltage ($T_A = +25^{\circ}C$, 10 Hz $\leq f \leq$ 100 kHz)	V _n	-	110	-	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	59	-	dB
Dropout Voltage (I _O = 1.0 A, T _J = +25°C)	V_{I} – V_{O}	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage	$\Delta V_{O}/\Delta T$				mV/°C
$I_{O} = 5.0 \text{ mA}, 0^{\circ}\text{C} \le T_{J} \le +125^{\circ}\text{C}$		-	-1.0	_	

MC7924B, MC7924C

 $\textbf{ELECTRICAL CHARACTERISTICS} \text{ (V}_{I} = -33 \text{ V}, \text{ I}_{O} = 500 \text{ mA}, \text{ Tlow*} < T_{J} < +125 ^{\circ}\text{C}, \text{ unless otherwise noted.)}$

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	-23	-24	-25	Vdc
Line Regulation (Note 6) (T _{.I} = +25°C, I _O = 100 mA)	Reg _{line}				mV
$-27 \text{ Vdc} \ge \text{V}_{\text{I}} \ge -38 \text{ Vdc}$		-	31	240	
$-30 \text{ Vdc} \ge \text{V}_1 \ge -36 \text{ Vdc}$ (T _{.1} = +25°C, I _O = 500 mA)		-	14	120	
–27 Vdc ≥ V _I ≥ –38 Vdc		-	118	470	
-30 Vdc ≥ V _I ≥ -36 Vdc		-	70	240	
Load Regulation, T _J = +25°C (Note 6)	Reg _{load}				mV
$5.0 \text{ mA} \le I_0 \le 1.5 \text{ A}$		-	150	480	
250 mA ≤ I _O ≤ 750 mA		_	85	240	
Output Voltage $-27 \text{ Vdc} \ge V_1 \ge -38 \text{ Vdc}, 5.0 \text{ mA} \le I_0 \le 1.0 \text{ A}, P \le 15 \text{ W}$	V _O	-22.8		-25.2	Vdc
<u> </u>		-22.0	_	-23.2	
Input Bias Current (T _J = +25°C)	I _{IB}	-	4.6	8.0	mA
Input Bias Current Change	Δl_{IB}				mA
$-27 \text{ Vdc} \ge V_1 \ge -38 \text{ Vdc}$		-	_	1.0	
5.0 mA ≤ I _O ≤ 1.5 A		-	_	0.5	
Output Noise Voltage ($T_A = +25^{\circ}C$, 10 Hz $\leq f \leq$ 100 kHz)	V _n	_	170	_	μV
Ripple Rejection (I _O = 20 mA, f = 120 Hz)	RR	-	56	_	dB
Dropout Voltage (I _O = 1.0 A, T _J = +25°C)	V _I -V _O	-	1.3	-	Vdc
Average Temperature Coefficient of Output Voltage $I_{O} = 5.0 \text{ mA}$, $Tlow^* \le T_{A} \le +125^{\circ}C$	$\Delta V_{O}/\Delta T$	_	-1.0	_	mV/°C

^{6.} Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

^{*}Tlow = -40°C for MC7924B and Tlow = 0°C for MC7924C.

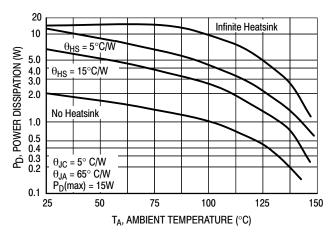


Figure 2. Worst Case Power Dissipation as a Function of Ambient Temperature

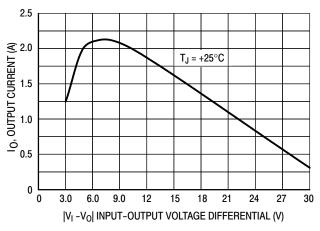


Figure 3. Peak Output Current as a Function of Input-Output Differential Voltage

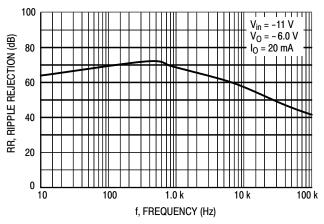


Figure 4. Ripple Rejection as a Function of Frequency

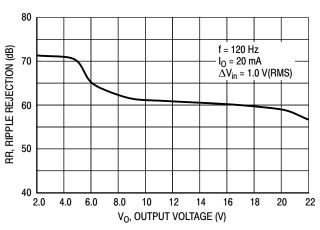


Figure 5. Ripple Rejection as a Function of Output Voltage

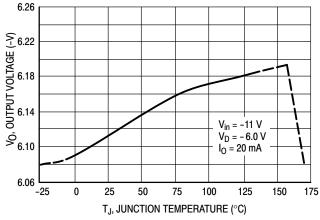


Figure 6. Output Voltage as a Function of Junction Temperature

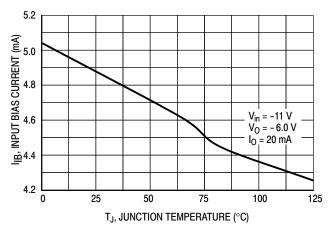


Figure 7. Quiescent Current as a Function of Temperature

APPLICATIONS INFORMATION

Design Considerations

The MC7900 Series of fixed voltage regulators are designed with Thermal overload Protection that shuts down the circuit when subjected to an excessive power overload condition. Internal Short Circuit Protection that limits the maximum current the circuit will pass, and Output Transistor Safe–Area Compensation that reduces the output short circuit current as the voltage across the pass transistor is increased.

In many low current applications, compensation capacitors are not required. However, it is recommended that the regulator input be bypassed with a capacitor if the regulator is connected to the power supply filter with long wire lengths, or if the output load capacitance is large. An input bypass capacitor should be selected to provide good high-frequency characteristics to insure stable operation under all load conditions. A 0.33 µF or larger tantalum, mylar, or other capacitor having low internal impedance at high frequencies should be chosen. The capacitor chosen should have an equivalent series resistance of less than 0.7Ω . The bypass capacitor should be mounted with the shortest possible leads directly across the regulators input terminals. Normally good construction techniques should be used to minimize ground loops and lead resistance drops since the regulator has no external sense lead. Bypassing the output is also recommended.

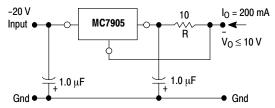
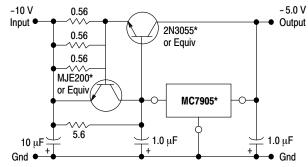


Figure 8. Current Regulator

The MC7905, -5.0 V regulator can be used as a constant current source when connected as above. The output current is the sum of resistor R current and quiescent bias current as follows:

$$I_{O} = \frac{5.0 \text{ V}}{\text{B}} + I_{B}$$

The quiescent current for this regulator is typically 4.3 mA. The 5.0 V regulator was chosen to minimize dissipation and to allow the output voltage to operate to within 6.0 V below the input voltage.



*Mounted on heatsink.

Figure 9. Current Boost Regulator

(-5.0 V @ 4.0 A, with 5.0 A Current Limiting)

When a boost transistor is used, short circuit currents are equal to the sum of the series pass and regulator limits, which are measured at 3.2 A and 1.8 A respectively in this case. Series pass limiting is approximately equal to 0.6 V/R_{SC}. Operation beyond this point to the peak current capability of the MC7905C is possible if the regulator is mounted on a heatsink; otherwise thermal shutdown will occur when the additional load current is picked up by the regulator.

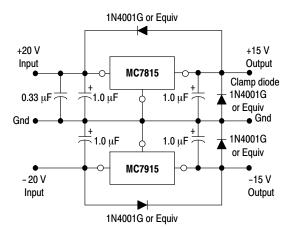


Figure 10. Operational Amplifier Supply

The MC7815 and MC7915 positive and negative regulators may be connected as shown to obtain a dual power supply for operational amplifiers. A clamp diode should be used at the output of the MC7815 to prevent potential latch—up problems whenever the output of the positive regulator (MC7815) is drawn below ground with an output current greater than 200 mA.

Protection Diodes

When external capacitors are used with MC7900 series regulator it is sometimes necessary to add protection diodes to prevent the capacitors from discharging through low current points into the regulator or from output polarity reversals. Generally, no protection diode is required for values of output capacitance less then $10\mu F$. Figure 11 shows the MC7915 with the recommended protection diodes.

• Opposite Polarity Protection

Diode D1 protects the regulator from output polarity reversals during startup, power off and short-circuit operation.

• Reverse-bias Protection

Diode D2 prevents output capacitor from discharging thru the MC7915 during an input short circuit or fast switch off of power supply.

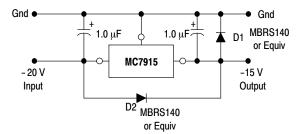


Figure 11. Protection Diodes

DEFINITIONS

Line Regulation – The change in output voltage for a change in the input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that the average chip temperature is not significantly affected.

Load Regulation – The change in output voltage for a change in load current at constant chip temperature.

Maximum Power Dissipation – The maximum total device dissipation for which the regulator will operate within specifications.

Input Bias Current – That part of the input current that is not delivered to the load.

Output Noise Voltage – The rms AC voltage at the output, with constant load and no input ripple, measured over a specified frequency range.

Long Term Stability – Output voltage stability under accelerated life test conditions with the maximum rated voltage listed in the devices' electrical characteristics and maximum power dissipation.

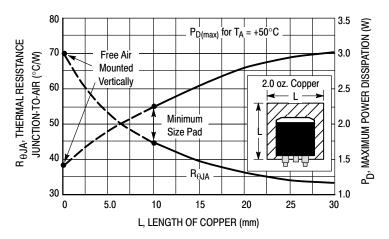


Figure 12. D²PAK Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

ORDERING INFORMATION

Device	Nominal Output Voltage	Output Voltage Tolerance	Package	Operating Temperature Range	Shipping _†
MC7905ACD2TR4G	-5.0 V	2%	D ² PAK (Pb-Free)	$T_J = 0$ °C to +125°C	800 Tape & Reel
MC7905BTG		4%	TO-220 (Pb-Free)	$T_J = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	50 Units/Rail
MC7905CTG			TO-220 (Pb-Free)	$T_J = 0$ °C to +125°C	50 Units/Rail
MC7906CTG	-6.0 V	4%	TO-220 (Pb-Free)	$T_J = 0$ °C to +125°C	50 Units/Rail
MC7912ACTG	-12 V	2%	TO-220 (Pb-Free)	T _J = 0°C to +125°C	50 Units/Rail
MC7912BD2TR4G		4%	D ² PAK (Pb-Free)	$T_{J} = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	800 Tape & Reel
MC7912BTG			TO-220 (Pb-Free)		50 Units/Rail
MC7912CTG			TO-220 (Pb-Free)	$T_J = 0$ °C to +125°C	50 Units/Rail
MC7915ACD2TG	– 15 V	2%	D ² PAK (Pb-Free)	T _J = 0°C to +125°C	50 Units/Rail
MC7915ACD2TR4G			D ² PAK (Pb-Free)		800 Tape & Reel
MC7915ACTG			TO-220 (Pb-Free)		50 Units/Rail
MC7915BTG		4%	TO-220 (Pb-Free)	$T_{J} = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	50 Units/Rail
MC7915BD2TR4G			D ² PAK (Pb-Free)		800 Tape & Reel
MC7915CD2TR4G			D ² PAK (Pb-Free)	$T_J = 0^{\circ}\text{C to } +125^{\circ}\text{C}$	800 Tape & Reel
MC7915CTG			TO-220 (Pb-Free)		50 Units/Rail
MC7918CTG			TO-220 (Pb-Free)		50 Units/Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

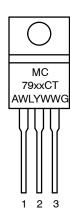
MARKING DIAGRAMS

TO-220 T SUFFIX CASE 221AB









D²PAK D2T SUFFIX CASE 936







xx = Nominal Voltage A = Assembly Location

WL = Wafer Lot
 Y = Year
 WW = Work Week
 G = Pb-Free Device

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS





TO-220, SINGLE GAUGE CASE 221AB-01 **ISSUE A**

DATE 16 NOV 2010

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCHES.

 3. DIMENSION 2 DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARTIES ARE ALLOWED.

 4. PRODUCT SHIPPED PRIOR TO 2008 HAD DIMENSIONS S = 0.045 0.055 INCHES (1.143 1.397 MM)

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.020	0.024	0.508	0.61
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04





STYLE 1: PIN 1. 2. 3. 4.	EMITTER	STYLE 2: PIN 1. 2. 3. 4.		STYLE 3: PIN 1. 2. 3. 4.	CATHODE ANODE GATE ANODE
STYLE 5: PIN 1. 2. 3. 4.	GATE DRAIN SOURCE DRAIN	STYLE 6: PIN 1. 2. 3. 4.	ANODE CATHODE ANODE CATHODE	STYLE 7: PIN 1. 2. 3. 4.	CATHODE ANODE CATHODE ANODE
STYLE 9: PIN 1. 2. 3. 4.	GATE COLLECTOR EMITTER COLLECTOR	STYLE 10: PIN 1. 2. 3. 4.	GATE	STYLE 11: PIN 1. 2. 3. 4.	DRAIN SOURCE GATE SOURCE

STYLE 4: PIN 1. 2. 3. 4.	MAIN TERMINAL 2
2. 3.	CATHODE ANODE EXTERNAL TRIP/DELAY ANODE

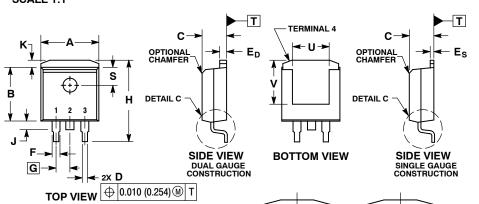
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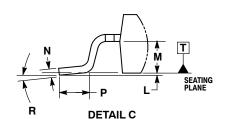
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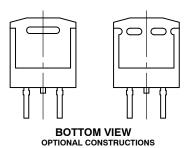


D²PAK CASE 936-03 ISSUE E

DATE 29 SEP 2015







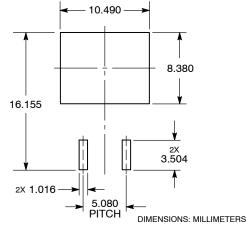
NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCHES. TAB CONTOUR OPTIONAL WITHIN DIMENSIONS

- A AND K.
 DIMENSIONS U AND V ESTABLISH A MINIMUM
- MOUNTING SURFACE FOR TERMINAL 4.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD
 FLASH OR GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.025 (0.635) MAXIMUM.
- SINGLE GAUGE DESIGN WILL BE SHIPPED AF-TER FPCN EXPIRATION IN OCTOBER 2011.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.386	0.403	9.804	10.236	
В	0.356	0.368	9.042	9.347	
С	0.170	0.180	4.318	4.572	
D	0.026	0.036	0.660	0.914	
ED	0.045	0.055	1.143	1.397	
Es	0.018	0.026	0.457	0.660	
F	0.051 REF		1.295 REF		
G	0.100 BSC		2.540 BSC		
Н	0.539	0.579	13.691 14.707		
J	0.125 MAX		3.175 MAX		
K	0.050	0.050 REF		1.270 REF	
L	0.000	0.010	0.000	0.254	
M	0.088	0.102	2.235	2.591	
N	0.018	0.026	0.457	0.660	
P	0.058	0.078	1.473	1.981	
R	0°	8°	0°	8°	
S	0.116 REF		2.946 REF		
U	0.200 MIN		5.080 MIN		
V	0.250 MIN		6.350 MIN		

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXXX = Specific Device Code

= Assembly Location = Wafer Lot 1

= Year Υ ww = Work Week G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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